

# THE AH3775 IS <u>NOT</u> RECOMMENDED FOR NEW DESIGNS. PLEASE USE THE AH3725.





#### HIGH-VOLTAGE MEDIUM-SENSITIVITY HALL-EFFECT LATCH

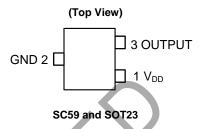
#### **Description**

The AH3775 is a high-voltage medium-sensitivity Hall-effect latch IC designed for commutation of brushless DC motors, flow meters, linear encoders and position sensors in industrial and consumer home appliances and personal care applications. To support the wide range of the demanding applications, the design is optimized to operate over the supply range of 3.0V to 28V. With chopper stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3775 provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a Zener clamp on the supply. The output has an overcurrent limit and a Zener clamp.

The single, open-drain output can be switched on with South pole of sufficient strength and switched off with North pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point (BoP) the output is switched on (pulled low). The output is held latched until the magnetic flux density reverses and becomes lower than the release point (BRP).

The magnetic operating and release polarity is opposite for SOT23 and SC59 packages. SOT23, SIP-3 (Bulk Pack) and SIP-3 (Ammo Pack) packages will require south pole to the part marking side to operate while SC59 will require south pole to the non-part marking side.

### **Pin Assignments**





SIP-3 (Bulk Pack) and SIP-3 (Ammo Pack)

#### **Features**

- Bipolar Latch Operation (South Pole: On, North Pole: Off)
- 3.0V to 28V Operating Voltage Range
- Medium Sensitivity: Bop and BRP of +70G and -70G Typical
- Single, Open-Drain Output with Overcurrent Limit
- Chopper Stabilized Design Provides:
  - Superior Temperature Stability
  - Minimal Switch Point Drift
  - Enhanced Immunity to Stress
- Good RF Noise Immunity
- Reverse Blocking Diode and Zener Clamp on Supply
- -40°C to +125°C Operating Temperature
- ESD (HBM): 6kV
- Industry Standard SC59, SOT23, SIP-3 (Bulk Pack) and SIP-3 (Ammo Pack) Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

### **Applications**

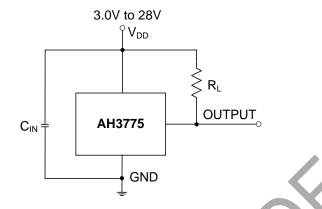
- Brushless DC motor commutation
- Revolution per minute (RPM) measurement
- Flow meters
- Angular and linear encoders and position sensors
- Contactless commutation, speed measurement and angular position sensing/indexing in consumer home appliances, office equipment and industrial applications

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



# **Typical Applications Circuit**



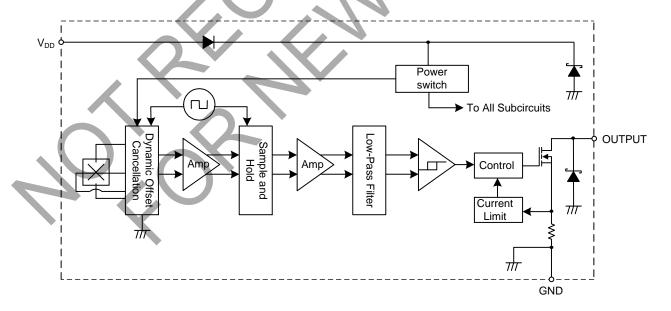
Note: 4. C<sub>IN</sub> is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF to 100nF. R<sub>L</sub> is the pullup resistor.

### **Pin Descriptions**

Packages: SC59, SOT23, SIP-3 (Bulk Pack) and SIP-3 (Ammo Pack)

Pin Number	Pin Name	Function
1	$V_{DD}$	Power Supply Input
2	GND	Ground
3	OUTPUT	Output Pin

## **Functional Block Diagram**





### Absolute Maximum Ratings (Notes 5 & 6) (@TA = +25°C, unless otherwise specified.)

Symbol	Characteristic		Value	Unit	
V <sub>DD</sub>	Supply Voltage (Note 6)	Supply Voltage (Note 6)			
VDDR	Reverse Supply Voltage		-32	V	
Vout_max	Output Off Voltage (Note 6)		32V	V	
Іоит	Continuous Output Current		60	mA	
lout_r	Reverse Output Current		-50	mA	
В	Magnetic Flux Density		Unlimited		
PD	Package Power Dissipation	SIP-3 (Bulk Pack) SIP-3 (Ammo Pack)	550	mW	
		SC59 and SOT23	230	mW	
Ts	Storage Temperature Range		-65 to +165	°C	
TJ	Maximum Junction Temperature		+150	°C	
ESD	Electrostatic Discharge Withstand Capability - Human E	Body Model	6	kV	

Notes:

- 5. Stresses greater than those listed under Absolute Maximum Ratings can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to Absolute Maximum Ratings for extended periods can affect device reliability.
- 6. The absolute maximum VDD of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

### Recommended Operating Conditions (@TA = -40°C to +125°C, unless otherwise specified.)

Symbol	Parameter	Conditions Rating	Unit
V <sub>DD</sub>	Supply Voltage	Operating 3.0 to 28V	V
TA	Operating Temperature Range	Operating -40 to +125	°C

#### Electrical Characteristics (Notes 7 & 8) (@TA = -40°C to +125°C, VDD = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OUT_ON</sub>	Output On Voltage	I <sub>OUT</sub> = 20mA, B > B <sub>OP</sub>	_	0.2	0.4	V
IOUT_OFF	Output Leakage Current	VOUT = 28V, B < BRP, Output off	_	< 0.1	10	μΑ
1	Supply Current	Output open, T <sub>A</sub> = +25°C	_	2.7	3	mA
I <sub>DD</sub>	Supply Current	Output open, T <sub>A</sub> = -40°C to +125°C	_	_	4	mA
1	Reverse Battery Current	$V_{DD} = -18V$ , $T_A = -40^{\circ}C$ to $+125^{\circ}C$	_	-0.01	1	mA
$I_{DD_R}$	Reverse Battery Current	$V_{DD} = -28V$ , $T_A = -40^{\circ}C$ to $+125^{\circ}C$	_	-0.01	1.5	mA
tsT	Device Startup Time	V <sub>DD</sub> ≥ 3V, B > B <sub>OP</sub> (Note 7)	_	10	_	μs
fc	Chopping Frequency	V <sub>DD</sub> = 3V to 28V	_	800	_	kHz
t <sub>d</sub>	The time delay from magnetic threshold reached to the start of the output rise or fall	(Note 9)	_	3.75	_	μs
tr	Output Rising Time (External pullup resistor R <sub>L</sub> and load capacitance dependent)	$R_L = 1k\Omega$ , $C_L = 20pF$	_	0.2	1	μs
tr	Output Falling Time (Internal switch resistance and load capacitance dependent)	$R_L = 1k\Omega$ , $C_L = 20pF$	_	0.1	1	μs
locL	Output Current Limit	B > B <sub>OP</sub> (Note 10)	30	_	55	mA
Vz	Zener Clamp Voltage	$I_{DD} = 5mA$	28	_	_	V

Notes:

- 7. When power is initially turned on, VDD must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the startup time of 10µs typical from the operating voltage reaching 3V.
- 8. Typical values are defined at T<sub>A</sub> = +25°C, V<sub>DD</sub> = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.
- 9. Guaranteed by design, process control and characterization, Not tested in production.
- 10. The device will limit the output current I<sub>OUT</sub> to current limit of I<sub>OCL</sub>.



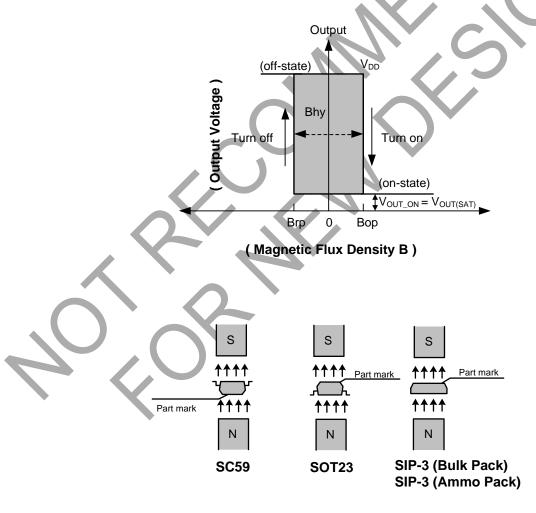
#### Magnetic Characteristics (Notes 11 & 12) (TA = -40°C to +125°C, VDD = 3.0V to 28V, unless otherwise specified)

(1mT=10 Gauss)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Вор		V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C	_	70	_	
(South pole to part marking side for SOT23 and SIP-3 (Bulk Pack)/SIP-3 (Ammo Pack) packages; South pole to the non-part marking side for SC59 package. See diagram below)	Operation Point	T <sub>A</sub> = -40°C to +125°C	50	70	90	
BRP		V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C	_	-70	_	0
(North pole to part marking side for SOT23 and SIP-3 (Bulk Pack)/SIP-3 (Ammo Pack) packages; North pole to the non-part marking side for SC59 package. See diagram below)	Release Point	T <sub>A</sub> = -40°C to +125°C	-90	-70	-50	Gauss
D (ID   ID   I)	Lhyatarasia (Nota 12)	V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C		140	_	
B <sub>HY</sub> ( B <sub>OPX</sub>  - B <sub>RPX</sub>  )	Hysteresis (Note 13)	T <sub>A</sub> = -40°C to +125°C	100	140	180	

Notes:

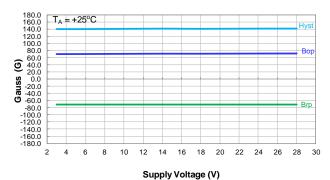
- 11. When power is initially turned on, V<sub>DD</sub> must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the startup time of 10µs typical from the operating voltage reaching 3V.
- 12. Typical values are defined at T<sub>A</sub> = +25°C, V<sub>DD</sub> = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.
- 13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.



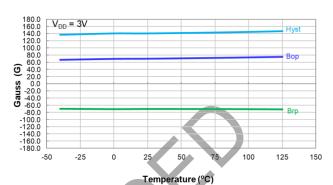


### **Typical Operating Characteristics**

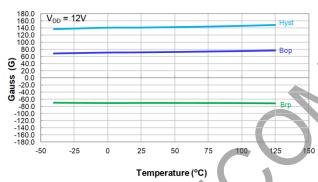
#### Magnetic Operating Switch Points - BOP and BRP



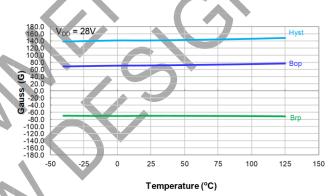
Switch Points Bop and Brp vs Supply Voltage



Switch Points Bop and Brp vs Temperature

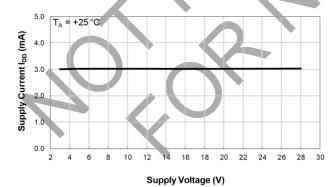


Switch Points Bop and Brp vs Temperature

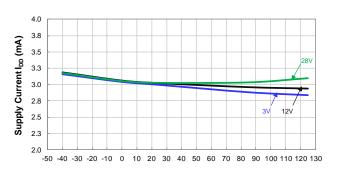


Switch Points Bop and Brp vs Temperature

#### **Supply Current**



Supply Current vs Supply Voltage

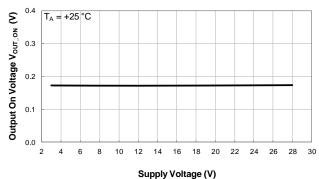


Temperature (°C)
Supply Current vs Temperature

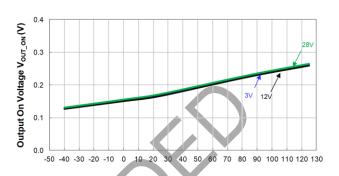


### **Typical Operating Characteristics** (continued)

#### **Output Switch On Voltage**

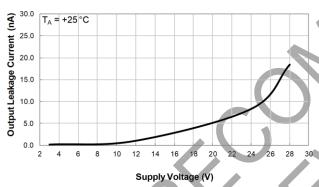


Output On Voltage vs Supply Voltage

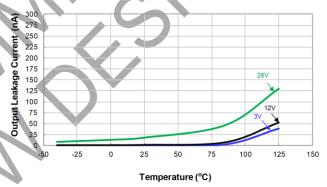


Temperature (°C)
Output On Voltage vs Temperature

### **Output Switch Leakage Current**

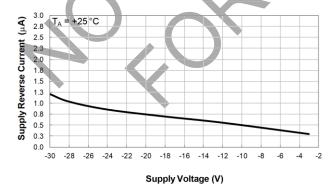


Output Leakage Current vs Supply Voltage

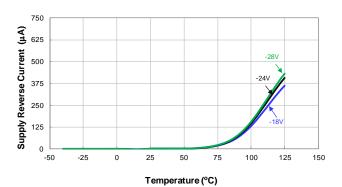


Output Leakage Current vs Temperature

#### **Supply Reverse Current**



Supply Reverse Current vs Supply Voltage



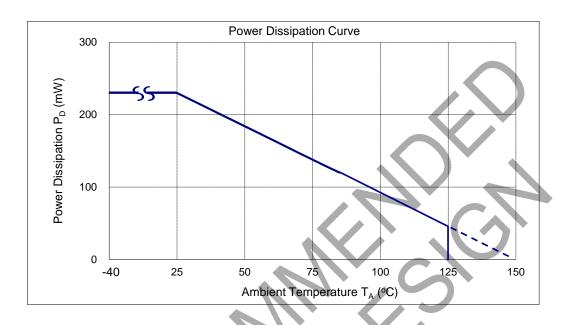
Supply Reverse Current vs Temperature



#### **Thermal Performance Characteristics**

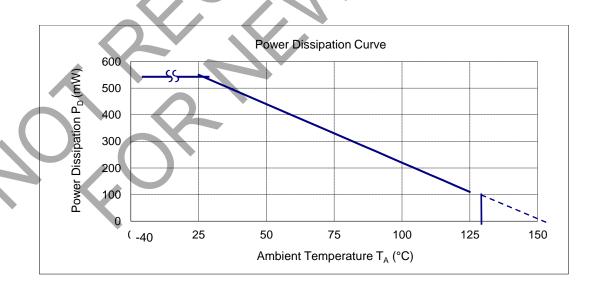
#### (1) Package Types: SC59 and SOT23

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



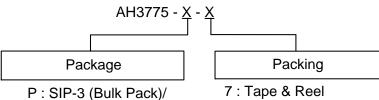
#### (2) Package Types: SIP-3 (Bulk Pack) and SIP-3 (Ammo Pack)

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0





### **Ordering Information**



SIP-3 (Ammo Pack)

SA: SOT23 W: SC59

7: Tape & Reel

A: Ammo Box (Note 14)

B: Bulk (Note 15)

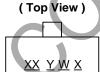
Part Number	Bookaga Codo	Package	Part Number Suffix	Packing			
Part Number	Package Code	rackaye	Part Number Sumx	Qty.	Carrier		
AH3775-P-A	Р	SIP-3 (Ammo Pack)	-A	4,000	Ammo Box		
AH3775-P-B	Р	SIP-3 (Bulk Pack)	-B	1,000	Bulk		
AH3775-SA-7	SA	SOT23	-7	3,000	7" Tape & Reel		
AH3775-W-7	W	SC59	-7	3,000	7" Tape & Reel		

Notes: 14. Ammo Box is for SIP-3 Spread Lead.

15. Bulk is for SIP-3 Straight Lead.

### **Marking Information**

#### (1) Package Types: SOT23 and SC59



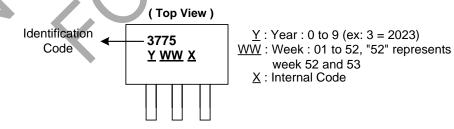
 $\frac{XX}{Y}$ : Identification Code  $\frac{Y}{Y}$ : Year 0 to 9 (ex: 3 = 2023)

W : Week : A to Z : week 1 to 26; a to z : week 27 to 52; z represents

week 52 and 53 X: Internal Code

Part Number	Package	Identification Code
AH3775-W-7	SC59	YZ
AH3775-SA-7	SOT23	ZE

#### (2) Package Types: SIP-3 (Bulk Pack) and SIP-3 (Ammo Pack)



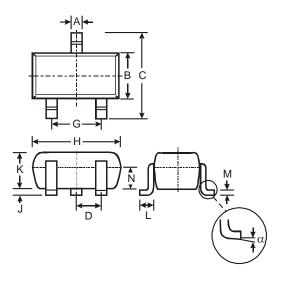
Part Number	Package	Identification Code
AH3775-P-A	SIP-3 (Ammo Pack)	3775
AH3775-P-B	SIP-3 (Bulk Pack)	3775



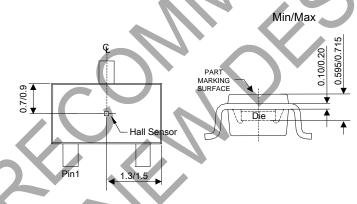
### Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (1) Package Type: SC59



	SC	59	
Dim	Min	Max	Тур
Α	0.35	0.50	0.38
В	1.50	1.70	1.60
С	2.70	3.00	2.80
D	-	1	0.95
G	-	-	1.90
Н	2.90	3.10	3.00
J	0.013	0.10	0.05
K.	1.00	1.30	1.10
L	0.35	0.55	0.40
М	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	
All	Dimens	ions in	mm



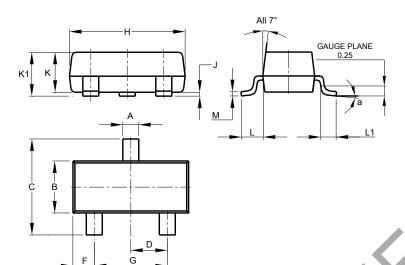
Sensor Location



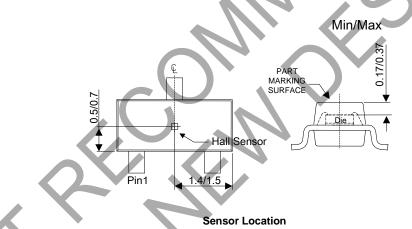
### Package Outline Dimensions (continued) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (2) Package Type: SOT23



	SO	T23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
В	1.20	1.40	1.30
С	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
Н	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
а		8°	
All	Dimens	ions in	mm

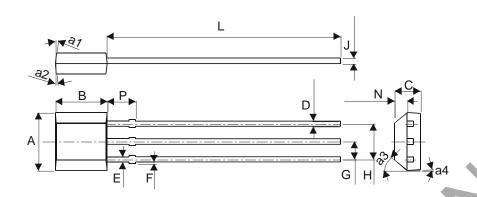




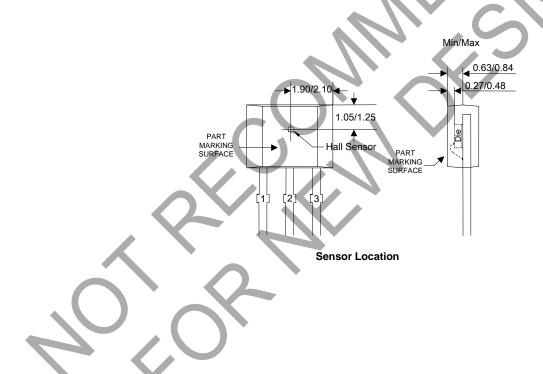
### Package Outline Dimensions (continued) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (3) Package Type: SIP-3 (Bulk Pack)



SIP-3 (Bulk Pack)		
Dim	Min	Max
Α	3.9	4.3
a1	5° Typ	
a2	5°Typ	
a3	45° Typ	
a4	3°Тур	
В	2.8	3.2
C	1.40	1.60
D	0.33	0.432
ш	0.40	0.508
F	0	0.2
G	1.24	1.30
Н	2.51	2.57
7	0.35	0.43
L	14.0	15.0
N	0.63	0.84
Р	1.55	-
All Dimensions in mm		

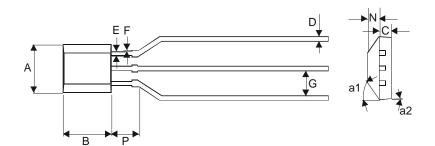




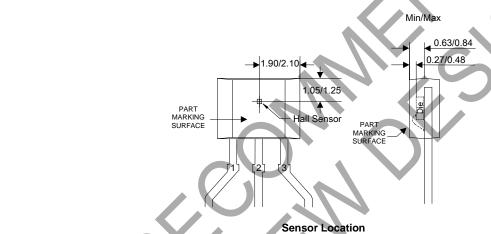
### Package Outline Dimensions (continued) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (4) Package Type: SIP-3 (Ammo Pack)



SIP-3 (Ammo Pack)		
Dim	Min	Max
Α	3.9	4.3
a1	45° Typ	
a2	3° Тур	
В	2.8	3.2
C	1.40	1.60
D	0.35	0.41
Е	0.43	0.48
F	0	0.2
G	2.4	2.9
2	0.63	0.84
P	1.55	-
All Dimensions in mm		

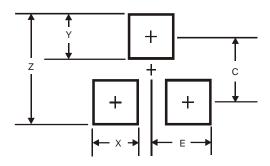




# Suggested Pad Layout

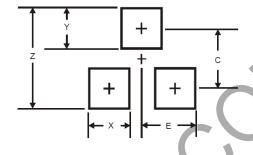
 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html for the latest version.$ 

#### (1) Package Type: SC59



Dimensions	Value (in mm)
Z	3.4
Х	0.8
Y	1.0
С	2.4
E	1.35

#### (2) Package Type: SOT23



Dimensions	Value (in mm)	
Z	2.9	
Х	0.8	
Y	0.9	
С	2.0	
E	1.35	



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